

# Model FD101

## Force Sensor Dies

### Description

Model FD101 is a piezoresistive force sensor die, which is made from monocrystalline silicon and specially designed for force measurement universally or sensor application to measure extreme low-level forces.

This model FD101 force sensor die has its four piezoresistive resistors each laid perpendicularly to the adjacent ones, similar pattern to the EB-type of metal foil strain gauges from BCM SENSOR. As a result, this force sensor die can be used to measure a force in all directions.

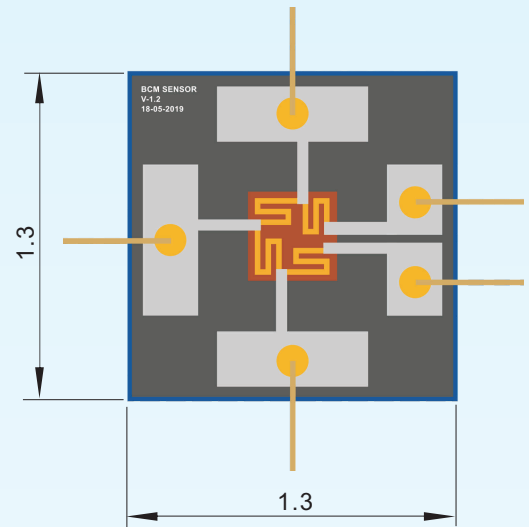
For example, if one of such the sensor dies is bonded on a bending beam, it forms a half bridge measuring circuit, or if two of such the sensor dies are bonded on the top- and bottom-surface of the bending beam respectively, they form a full bridge measuring circuit. In case of an either tension or compression beam where this sensor die is bonded on, it can form a full bridge measuring circuit. In addition, if this sensor die is bonded on a shear beam or torsion beam, it can also form a full bridge circuit to measure shear force or torque.

The four piezoresistive resistors of the FD101 force sensor die constitute a full-bridge circuit, resulting in a high sensitivity for low-level force measurement down to a few microstrains.

On the FD101, its Wheatstone bridge circuit is configured to the open-bridge circuit of 5 solder pads, on which gold leads can be attached on request. 5 solder pads also bring advantage to facilitation of its zero-offset adjustment and temperature compensation. As there is no signal-conditioning circuitry on this sensor die, its output signal is directly from its Wheatstone bridge circuit.

Thanks to MEMS technology, the FD101 features a small size (1.3mm x 1.3mm) and capacity of high volume per batch in mass production.

### Dimensions



#### Notes:

- 1) Thickness is 0.1mm.
- 2) All dimensions are in mm.

### Features

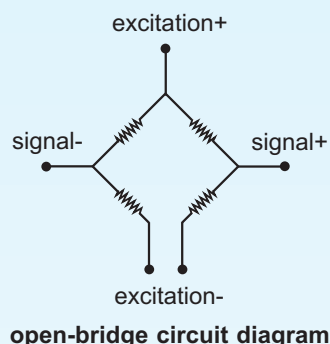
- excellent non-linearity up to:  $\pm 0.5\%$ fs
- high output sensitivity:  $\geq 29\text{mV/V}$
- small foot-print, high product rate per wafer for cost-effective application
- gold leads on solder pads available on request

### Applications

- automation: mass production of force sensors, force switches, and force controllers
- medical: clinical devices and patient monitoring systems (e.g. dialysis instruments)
- stress analysis: stress, strain, and vibration monitoring
- consumer: consumer electronics

**BCM SENSOR TECHNOLOGIES BVBA**

### Wheatstone Bridge Circuit Diagram



### Technical Data

Parameters		Units	Specifications	Notes
measuring range		$\mu\epsilon$	5~500	
safe load limit		%fs	200	1
ultimate overload		%fs	400	1
full scale output (fso)		mV	$\geq 148$	2 & 3
excitation	voltage	Vdc	5 (typical), or any voltage in the range of 1, ..., 12Vdc	
	current	mA	1 (typical), or any current in the range of 0.3, ..., 4mA	
zero offset		mV	$\leq \pm 42$	3
non-linearity (NL)		%fs	$\leq \pm 0.5$	4
hysteresis (HY)		%fs	$\leq \pm 0.15$	
repeatability (RP)		%fs	$\leq \pm 0.15$	
long-term stability		%fs/year	$\leq \pm 0.2$	
bridge resistance		k $\Omega$	2.4 $\pm$ 0.2	
storage temperature range		$^{\circ}\text{C}$	-55 ~ +85	
operating temperature range		$^{\circ}\text{C}$	-55 ~ +75	
temp. coeff. (TC) of bridge resistance		%/ $^{\circ}\text{C}$	0.11 $\pm$ 0.02	5
TC of zero offset		%fso/ $^{\circ}\text{C}$	$\leq \pm 0.08$	6
TC of span		%fso/ $^{\circ}\text{C}$	$\leq  -0.71 $	6
thermal HY of zero offset		%fso/ $^{\circ}\text{C}$	$\leq \pm 0.04$	
electrical interface			solder pads (standard), gold leads	7
dimensions		mm	1.3 x 1.3 x 0.1	

General conditions for measurements: temperature = 25 $^{\circ}\text{C}$ , humidity = 40%RH.

- Notes:
1. fs refers to full scale strain.
  2. Measured at nominal strain of 500 $\mu\epsilon$  with orientation laterally along any of the resistor of the sensor die.
  3. Measured at 5Vdc excitation.
  4. Calculated according to Terminal Base Line (the endpoint method).
  5. Calculated as a rate of resistance change between -55 $^{\circ}\text{C}$  and +75 $^{\circ}\text{C}$ , and normalized by the resistance at 25 $^{\circ}\text{C}$ .
  6. Calculated as a rate of output change between -55 $^{\circ}\text{C}$  and +75 $^{\circ}\text{C}$ , and normalized by the output at 25 $^{\circ}\text{C}$ , when the die is not temperature compensated.
  7. Dimensions of gold leads:  $\varnothing$ 0.03mm diameter, and 10mm length.

# Model FD101

## Force Sensor Dies



### Ordering Information

<b>position (pos.) 1: model</b>							
FD101							
<b>pos. 2: nominal strain</b>							
500 = 500µε							
<b>pos. 3: output signal</b>							
148mV							
<b>pos. 4: non-linearity</b>							
0.5%fs							
<b>pos. 5: bridge type</b>							
OB = open-bridge circuit							
<b>pos. 6: package</b>							
X = individually packaged die in plastic package (standard for sample order)							
Y = diced wafer on tape (standard for volume order)							
Z = non-diced wafer							
<b>pos. 7: solder-pad finishing</b>							
SP = naked solder pads (standard)							
GL = gold leads (only available for package X)							
<b>pos. 8: customized specifications</b>							
“(*)” is necessary only if any customized parameter is required, otherwise it is neglectable.							
pos.1	pos. 2	pos. 3	pos. 4	pos. 5	pos. 6	pos. 7	pos. 8

### Examples of Ordering Code

- standard sensor die:

FD101-500-148mV-0.5%fs-OB-Y

The listed dimensions, specifications and ordering information are subject to change without prior notice.

**BCM SENSOR TECHNOLOGIES BVBA**

